

# LT1092A Series

Molded Interconnection  
Device

## ■ Model No.

LT1D92A Red                  GaAsP/GaP

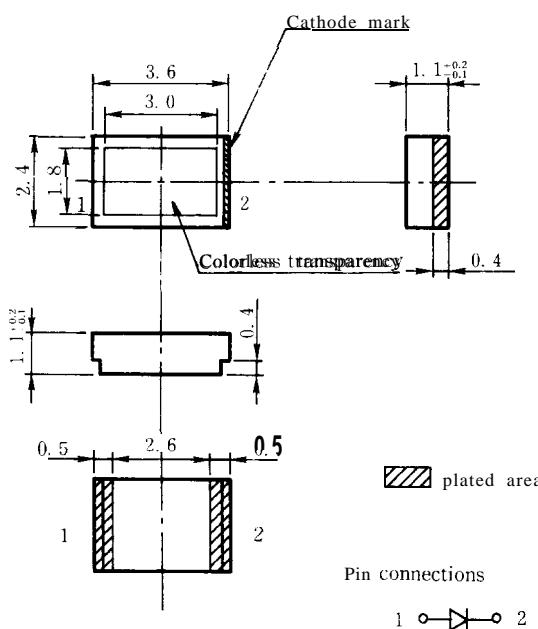
LT1E92A Yellow-green GaP

## ■ Features

1. Radiation size 1.8×3.0mm
2. Colorless transparency lens type
3. Taped models : Tape width 8mm, 3,000 pcs/reel

## ■ Outline Dimensions

(Unit : mm)



Unspecified tolerance :  $\pm 0.1\text{mm}$

Regarding the taping specifications, please see "Taped Models" of Appendix

S H A R P

**LT1□92A****■Absolute Maximum Ratings**

(Ta = 25°C)

Parameter	Symbol	LT1D92A						Unit
		LT1E92A						
Power dissipation	P	84						mW
Continuous forward current	IF	30						mA
*1 Peak forward current	I <sub>FM</sub>	50						mA
Derating factor	DC	0.40						mA/°C
	Pulse	0.67						mA/°C
Reverse voltage	V <sub>R</sub>	5						V
Operating temperature	T <sub>opr</sub>	-25 to +85						°C
Storage temperature	T <sub>stg</sub>	-25 to +100						°C

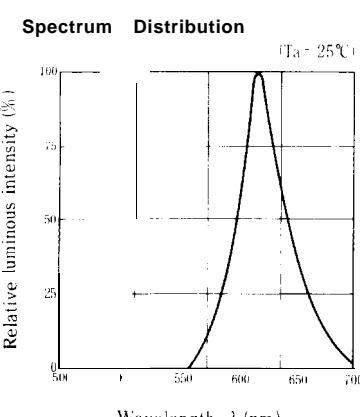
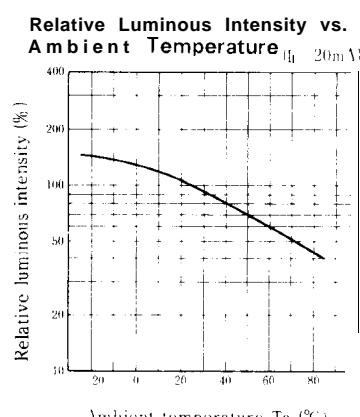
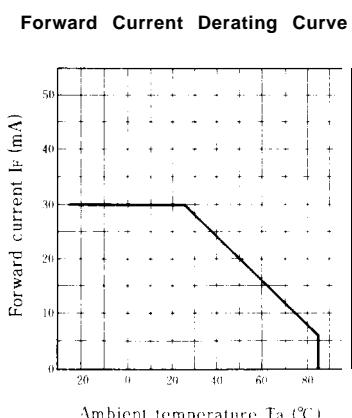
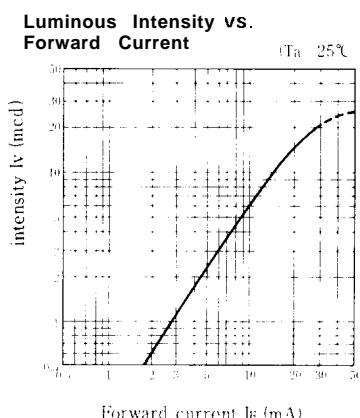
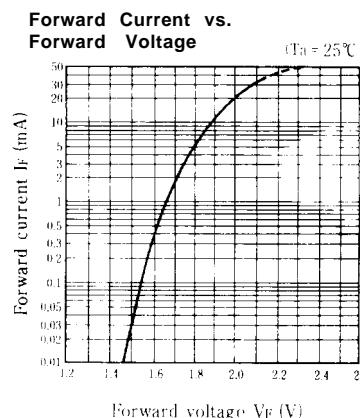
\*1 Duty ratio=1/10, Pulse width=0.1 ms

**LT1D92A(Red)****■ Electro-optical Characteristics**

(Ta = 25°C)

Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V <sub>F</sub>	LT1D92A	I <sub>F</sub> = 20mA	2.0	2.8		V
*2 Luminous intensity	I <sub>v</sub>	LT1D92A	I <sub>F</sub> = 20mA	4.3	15.0	--	mcd
Peak emission wavelength	λ <sub>P</sub>	LT1D92A	I <sub>F</sub> = 20mA		635		nm
Spectrum radiation bandwidth	△λ	LT1D92A	I <sub>F</sub> = 20mA		35	--	nm
Reverse current	I <sub>R</sub>	LT1D92A	V <sub>R</sub> = 4V			10	μA
Terminal capacitance	C <sub>t</sub>	LT1D92A	V = 0V f = 1MHz	20			pF
Response frequency	f <sub>c</sub>	LT1D92A					MHz

\*2 Tolerance : ±15%

**■ Characteristics Diagrams**

## LTI E92A(Yellow-green)

(Ta = 25°C)

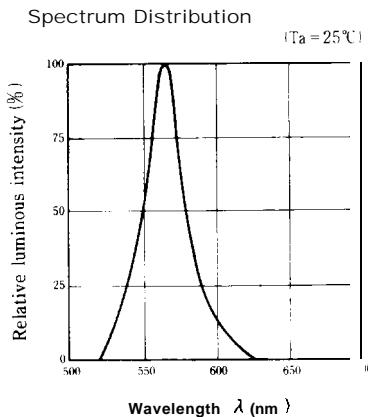
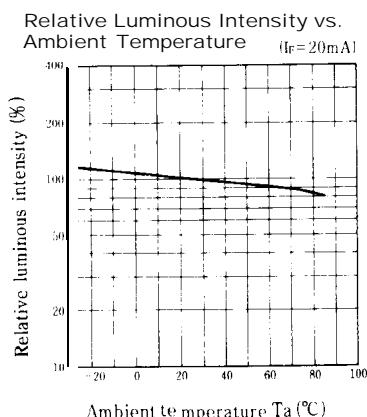
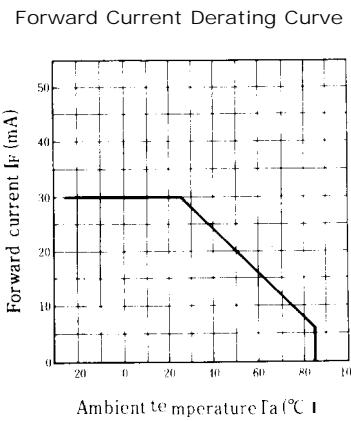
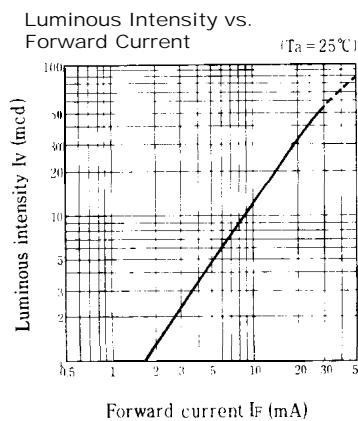
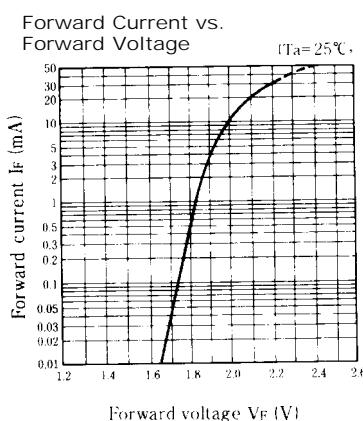
## ■ Electro-optical Characteristics

Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V <sub>F</sub>	LT1E92A	I <sub>F</sub> = 20mA		2.1	2.8	V
		LT1E92A	I <sub>F</sub> = 20mA	13.6	32.0	-	
*2 Luminous intensity	I <sub>V</sub>	LT1E92A	I <sub>F</sub> = 20mA		565	-	mcd
		LT1E92A	I <sub>F</sub> = 20mA	30	-	-	
Peak emission wavelength	λ <sub>P</sub>	LT1E92A	I <sub>F</sub> = 20mA			-	nm
Spectrum radiation bandwidth	△λ	LT1E92A	I <sub>F</sub> = 20mA			-	nm
		LT1E92A	V = 4V			10	
Reverse current	I <sub>R</sub>	LT1E92A	V = 0V f = 1MHz	--	35	-	μA
		LT1E92A	V = 0V f = 1MHz	-		-	
Terminal capacitance	C <sub>t</sub>	LT1E92A	V = 0V f = 1MHz	--		-	pF
Response frequency	f <sub>c</sub>	LT1E92A	V = 0V f = 1MHz	-		-	MHz

\*2 Tolerance : ±15%

## Characteristics Diagrams

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SHARP